Michael Lorenz

List of Publications by Citations

351 papers	11,289 citations	49 h-index	93 g-index
370 ext. papers	12,063 ext. citations	3.1 avg, IF	5.87 L-index

#	Paper	IF	Citations
351	Raman scattering in ZnO thin films doped with Fe, Sb, Al, Ga, and Li. *Applied Physics Letters*, **2003**, 83, 1974-1976	3.4	551
350	Infrared dielectric functions and phonon modes of high-quality ZnO films. *Journal of Applied Physics* , **2003**, 93, 126-133	2.5	545
349	High electron mobility of epitaxial ZnO thin films on c-plane sapphire grown by multistep pulsed-laser deposition. *Applied Physics Letters*, **2003**, 82, 3901-3903	3.4	539
348	Zinc oxide nanorod based photonic devices: recent progress in growth, light emitting diodes and lasers. *Nanotechnology*, **2009**, 20, 332001	3.4	503
347	Room temperature ferromagnetism in ZnO films due to defects. *Applied Physics Letters*, **2008**, 92, 082508	3.4	310
346	Whispering gallery modes in nanosized dielectric resonators with hexagonal cross section. *Physical Review Letters*, **2004**, 93, 103903	7.4	270
345	Defect-induced magnetic order in pure ZnO films. *Physical Review B*, **2009**, 80,	3.3	257
344	The 2016 oxide electronic materials and oxide interfaces roadmap. *Journal Physics D: Applied Physics*, **2016**, 49, 433001	3	204
343	MgxZn1⊠O(0?x. *Applied Physics Letters*, **2005**, 86, 143113	3.4	181
342	Room temperature ferromagnetism in carbon-implanted ZnO. *Applied Physics Letters*, **2008**, 93, 232507	3.4	178
341	Whispering gallery mode lasing in zinc oxide microwires. *Applied Physics Letters*, **2008**, 92, 241102	3.4	178
340	Transparent flexible thermoelectric material based on non-toxic earth-abundant p-type copper iodide thin film. *Nature Communications*, **2017**, 8, 16076	17.4	164
339	Dielectric functions (1 to 5 eV) of wurtzite MgxZn1⊠O (x?0.29) thin films. *Applied Physics Letters*, **2003**, 82, 2260-2262	3.4	157
338	Mean barrier height of Pd Schottky contacts on ZnO thin films. *Applied Physics Letters*, **2006**, 88, 092102	3.4	146
337	Two-dimensional electron gas density in Al1⊠InxN/AlN/GaN heterostructures (0.03⊠⊠.23). *Journal of Applied Physics*, **2008**, 103, 093714	2.5	138
336	Optical and electrical properties of epitaxial (Mg,Cd)xZn1⊠O, ZnO, and ZnO:(Ga,Al) thin films on c-plane sapphire grown by pulsed laser deposition. *Solid-State Electronics*, **2003**, 47, 2205-2209	1.7	130
335	Defects in virgin and N+-implanted ZnO single crystals studied by positron annihilation, Hall effect, and deep-level transient spectroscopy. *Physical Review B*, **2006**, 74,	3.3	129

334	Room-temperature synthesized copper iodide thin film as degenerate p-type transparent conductor with a boosted figure of merit. *Proceedings of the National Academy of Sciences of the United States of America*, **2016**, 113, 12929-12933	11.5	126
333	Recent progress on ZnO-based metal-semiconductor field-effect transistors and their application in transparent integrated circuits. *Advanced Materials*, **2010**, 22, 5332-49	24	122
332	Transparent semiconducting oxides: materials and devices. *Physica Status Solidi (A) Applications and Materials Science*, **2010**, 207, 1437-1449	1.6	120
331	Cuprous iodide a p-type transparent semiconductor: history and novel applications. *Physica Status Solidi (A) Applications and Materials Science*, **2013**, 210, 1671-1703	1.6	111
330	Phosphorus acceptor doped ZnO nanowires prepared by pulsed-laser deposition. *Nanotechnology*, **2007**, 18, 455707	3.4	96
329	Lateral homogeneity of Schottky contacts on n-type ZnO. *Applied Physics Letters*, **2004**, 84, 79-81	3.4	95
328	Cuprous iodide a p-type transparent semiconductor: history and novel applications (Phys. Status Solidi A 9?013). *Physica Status Solidi (A) Applications and Materials Science*, **2013**, 210,	1.6	86
327	Large-area double-side pulsed laser deposition of YBa2Cu3O7? thin films on 3-in. sapphire wafers. *Applied Physics Letters*, **1996**, 68, 3332-3334	3.4	85
326	Multiferroic BaTiO3?BiFeO3composite thin films and multilayers: strain engineering and magnetoelectric coupling. *Journal Physics D: Applied Physics*, **2014**, 47, 135303	3	83
325	Anionic and cationic substitution in ZnO. *Progress in Solid State Chemistry*, **2009**, 37, 153-172	8	81
324	Room temperature ferromagnetism in Mn-doped ZnO films mediated by acceptor defects. *Applied Physics Letters*, **2007**, 91, 092503	3.4	80
323	Metal-insulator transition in Co-doped ZnO: Magnetotransport properties. *Physical Review B*, **2006**, 73,	3.3	77
322	Spatially Inhomogeneous Impurity Distribution in ZnO Micropillars. *Nano Letters*, **2004**, 4, 797-800	11.5	74
321	Infrared optical properties of MgxZn1?O thin films (0?x?1): Long-wavelength optical phonons and dielectric constants. *Journal of Applied Physics*, **2006**, 99, 113504	2.5	72
320	Room-temperature Domain-epitaxy of Copper Iodide Thin Films for Transparent CuI/ZnO Heterojunctions with High Rectification Ratios Larger than 10(9). *Scientific Reports*, **2016**, 6, 21937	4.9	69
319	Properties of reactively sputtered Ag, Au, Pd, and Pt Schottky contacts on n-type ZnO. *Journal of Vacuum Science & Technology B*, **2009**, 27, 1769		68
318	Electrical and magnetic properties of RE-doped ZnO thin films (RE = Gd, Nd). *Superlattices and Microstructures*, **2007**, 42, 231-235	2.8	67
317	Whispering gallery modes in zinc oxide micro- and nanowires. *Physica Status Solidi (B): Basic Research*, **2010**, 247, 1282-1293	1.3	66

316	UV optical properties of ferromagnetic Mn-doped ZnO thin films grown by PLD. *Thin Solid Films*, **2005**, 486, 117-121	2.2	65
315	Infrared dielectric functions and phonon modes of wurtzite MgxZn1□O (x?0.2). *Applied Physics Letters*, **2002**, 81, 2376-2378	3.4	64
314	Deep acceptor states in ZnO single crystals. *Applied Physics Letters*, **2006**, 89, 092122	3.4	63
313	Tin-assisted heteroepitaxial PLD-growth of □Ga2O3 thin films with high crystalline quality. *APL Materials*, **2019**, 7, 022516	5.7	63
312	Occurrence of rotation domains in heteroepitaxy. *Physical Review Letters*, **2010**, 105, 146102	7.4	62
311	ZnO metal-semiconductor field-effect transistors with Ag-Schottky gates. *Applied Physics Letters*, **2008**, 92, 192108	3.4	62
310	s□ exchange interaction induced magnetoresistance in magnetic ZnO. *Physical Review B*, **2007**, 76,	3.3	61
309	Lattice parameters and Raman-active phonon modes of □(AlxGa1□)2O3. *Journal of Applied Physics* , **2015**, 117, 125703	2.5	59
308	Structural characterization of a-plane Zn1□CdxO (0?x?0.085) thin films grown by metal-organic vapor phase epitaxy. *Journal of Applied Physics*, **2006**, 99, 023514	2.5	59
307	Electron paramagnetic resonance of Zn1□MnxO thin films and single crystals. *Physical Review B*, **2005**, 72,	3.3	58
306	Defect-induced ferromagnetism in undoped and Mn-doped zirconia thin films. *Physical Review B*, **2010**, 82,	3.3	57
305	Spin manipulation in Co-doped ZnO. *Physical Review Letters*, **2008**, 101, 076601	7.4	55
304	Refractive indices and band-gap properties of rocksalt MgxZn1□O (0.68?x?1). *Journal of Applied Physics*, **2006**, 99, 123701	2.5	51
303	Hard amorphous CSi x N y thin films deposited by RF nitrogen plasma assisted pulsed laser ablation of mixed graphite/Si 3 N 4 -targets. *Thin Solid Films*, **1999**, 348, 103-113	2.2	50
302	Correlation of magnetoelectric coupling in multiferroic BaTiO3-BiFeO3 superlattices with oxygen vacancies and antiphase octahedral rotations. *Applied Physics Letters*, **2015**, 106, 012905	3.4	49
301	Resistive hysteresis and interface charge coupling in BaTiO3-ZnO heterostructures. *Applied Physics Letters*, **2009**, 94, 142904	3.4	49
300	Temperature-dependent dielectric and electro-optic properties of a ZnO-BaTiO3-ZnO heterostructure grown by pulsed-laser deposition. *Applied Physics Letters*, **2005**, 86, 091904	3.4	49
299	High-quality Y-Ba-Cu-O thin films by PLD-ready for market applications. *IEEE Transactions on Applied Superconductivity*, **2001**, 11, 3209-3212	1.8	49

298	Structural and optical properties of (In,Ga)2O3 thin films and characteristics of Schottky contacts thereon. *Semiconductor Science and Technology*, **2015**, 30, 024005	1.8	47
297	Low-temperature processed Schottky-gated field-effect transistors based on amorphous gallium-indium-zinc-oxide thin films. *Applied Physics Letters*, **2010**, 97, 243506	3.4	47
296	Donor-like defects in ZnO substrate materials and ZnO thin films. *Applied Physics A: Materials Science and Processing*, **2007**, 88, 135-139	2.6	47
295	Luminescence and surface properties of MgxZn1−xO thin films grown by pulsed laser deposition. *Journal of Applied Physics*, **2007**, 101, 083521	2.5	47
294	Cathodoluminescence of selected single ZnO nanowires on sapphire. *Annalen Der Physik*, **2004**, 13, 39-42	2.6	47
293	Fe-implanted ZnO: Magnetic precipitates versus dilution. *Journal of Applied Physics*, **2008**, 103, 023902	2.5	46
292	Microstructure defects in YBCO thin films. *Physica C: Superconductivity and Its Applications*, **1995**, 243, 281-293	1.3	46
291	Effect of rare-earth ion doping on the multiferroic properties of BiFeO3thin films grown epitaxially on SrTiO3(1 0 0). *Journal Physics D: Applied Physics*, **2013**, 46, 175006	3	45
290	Lattice parameters and Raman-active phonon modes of (InxGa1−x)2O3 for x . *Journal of Applied Physics*, **2014**, 116, 013505	2.5	45
289	p-type conducting ZnO:P microwires prepared by direct carbothermal growth. *Physica Status Solidi - Rapid Research Letters*, **2008**, 2, 37-39	2.5	44
288	Ordered growth of tilted ZnO nanowires: morphological, structural and optical characterization. *Nanotechnology*, **2007**, 18, 195303	3.4	42
287	Pulsed Laser Deposition of ZnO-Based Thin Films. *Springer Series in Materials Science*, **2008**, 303-357	0.9	40
286	Exciton–polariton formation at room temperature in a planar ZnO resonator structure. *Applied Physics B: Lasers and Optics*, **2008**, 93, 331-337	1.9	40
285	Mott variable-range hopping and weak antilocalization effect in heteroepitaxial Na2IrO3 thin films. *Physical Review B*, **2013**, 88,	3.3	39
284	Homogeneous core/shell ZnO/ZnMgO quantum well heterostructures on vertical ZnO nanowires. *Nanotechnology*, **2009**, 20, 305701	3.4	39
283	Magnetoresistance and anomalous Hall effect in magnetic ZnO films. *Journal of Applied Physics*, **2007**, 101, 063918	2.5	39
282	Side-selective and non-destructive determination of the critical current density of double-sided superconducting thin films. *Physica C: Superconductivity and Its Applications*, **1996**, 265, 335-340	1.3	39
281	Ferromagnetic transition metal implanted ZnO: A diluted magnetic semiconductor?. *Vacuum*, **2009**, 83, S13-S19	3.7	38

280	Self-organized growth of ZnO-based nano- and microstructures. *Physica Status Solidi (B): Basic Research*, **2010**, 247, 1265-1281	1.3	38
279	Homoepitaxy of ZnO by pulsed-laser deposition. *Physica Status Solidi - Rapid Research Letters*, **2007**, 1, 129-131	2.5	38
278	Room-temperature ferromagnetic Mn-alloyed ZnO films obtained by pulsed laser deposition. *Journal of Magnetism and Magnetic Materials*, **2006**, 307, 212-221	2.8	38
277	UV–VUV spectroscopic ellipsometry of ternary MgxZn1−xO (0≤x≤0.53) thin films. *Thin Solid Films*, **2004**, 455-456, 500-504	2.2	38
276	Dielectric function in the spectral range (0.5–8.5)eV of an (Alx Ga1−x)2O3 thin film with continuous composition spread. *Journal of Applied Physics*, **2015**, 117, 165307	2.5	37
275	Paramagnetism in Co-doped ZnO films. *Journal Physics D: Applied Physics*, **2009**, 42, 085001	3	36
274	ac susceptibility of structured YBa2Cu3O7 thin films in transverse magnetic ac fields. *Physical Review B*, **1997**, 55, 11816-11822	3.3	36
273	Spatial fluctuations of optical emission from single ZnO/MgZnO nanowire quantum wells. *Nanotechnology*, **2008**, 19, 115202	3.4	36
272	Interface polarization coupling in piezoelectric-semiconductor ferroelectric heterostructures. *Physical Review B*, **2010**, 81,	3.3	35
271	Two-dimensional ZnO:Al nanosheets and nanowalls obtained by Al2O3-assisted carbothermal evaporation. *Thin Solid Films*, **2005**, 486, 191-194	2.2	34
270	Structural and magnetic properties of epitaxial magnetite thin films prepared by pulsed laser deposition. *Journal of Magnetism and Magnetic Materials*, **1995**, 140-144, 725-726	2.8	34
269	A comparison between ZnO films doped with 3d and 4f magnetic ions. *Thin Solid Films*, **2007**, 515, 8761-8763	2.2	33
268	Visible-blind and solar-blind ultraviolet photodiodes based on (InxGa1−x)2O3. *Applied Physics Letters*, **2016**, 108, 123503	3.4	33
267	Control of interface abruptness of polar MgZnO/ZnO quantum wells grown by pulsed laser deposition. *Applied Physics Letters*, **2010**, 97, 052101	3.4	32
266	Exchange anisotropy in epitaxial Fe3O4/CoO and Fe3O4/CoxFe3−xO4 bilayers grown by pulsed laser deposition. *Journal of Applied Physics*, **1998**, 84, 5097-5104	2.5	32
265	Infrared dielectric functions and crystal orientation of a-plane ZnO thin films on r-plane sapphire determined by generalized ellipsometry. *Thin Solid Films*, **2004**, 455-456, 161-166	2.2	31
264	Rectifying semiconductor-ferroelectric polarization loops and offsets in Pt–BaTiO3–ZnO–Pt thin film capacitor structures. *Thin Solid Films*, **2005**, 486, 153-157	2.2	31
263	Microcracks observed in epitaxial thin films of YBa2 Cu3O7−δ and GdBa2Cu3O7−δ *Physica Status Solidi A*, **1995**, 150, 381-394		31

262	Formation of a two-dimensional electron gas in ZnO/MgZnO single heterostructures and quantum wells. *Thin Solid Films*, **2009**, 518, 1048-1052	2.2	30
261	Optical properties of homo- and heteroepitaxial ZnO/MgxZn1-xO single quantum wells grown by pulsed-laser deposition. *Journal of Luminescence*, **2010**, 130, 520-526	3.8	30
260	Pulsed-laser deposition and characterization of ZnO nanowires with regular lateral arrangement. *Applied Physics A: Materials Science and Processing*, **2007**, 88, 31-34	2.6	30
259	25 years of pulsed laser deposition. *Journal Physics D: Applied Physics*, **2014**, 47, 030301	3	29
258	Tungsten oxide as a gate dielectric for highly transparent and temperature-stable zinc-oxide-based thin-film transistors. *Advanced Materials*, **2011**, 23, 5383-6	24	29
257	Electron paramagnetic resonance in transition metal-doped ZnO nanowires. *Journal of Applied Physics*, **2007**, 101, 024324	2.5	29
256	Infrared dielectric function and phonon modes of Mg-rich cubic MgxZn1⊠O(x?0.67) thin films on sapphire (0001). *Applied Physics Letters*, **2004**, 85, 905-907	3.4	29
255	Microstructure and microwave surface resistance of typical YBaCuO thin films on sapphire and LaAlO3. *Superconductor Science and Technology*, **1999**, 12, 366-375	3.1	29
254	Optical and structural properties of MgZnO/ZnO hetero- and double heterostructures grown by pulsed laser deposition. *Applied Physics A: Materials Science and Processing*, **2007**, 88, 99-104	2.6	28
253	Large-area and double-sided pulsed laser deposition of Y-Ba-Cu-O thin films applied to HTSC microwave devices. *IEEE Transactions on Applied Superconductivity*, **1997**, 7, 1240-1243	1.8	27
252	High electron mobility of phosphorous-doped homoepitaxial ZnO thin films grown by pulsed-laser deposition. *Journal of Applied Physics*, **2008**, 104, 013708	2.5	27
251	Photocurrent spectroscopy of deep levels in ZnO thin films. *Physical Review B*, **2007**, 76,	3.3	27
250	Electronic properties of defects in pulsed-laser deposition grown ZnO with levels at 300 and 370meV below the conduction band. *Physica B: Condensed Matter*, **2007**, 401-402, 378-381	2.8	27
249	Fast, high-efficiency, and homogeneous room-temperature cathodoluminescence of ZnO scintillator thin films on sapphire. *Applied Physics Letters*, **2006**, 89, 243510	3.4	27
248	Local lattice distortions in oxygen deficient Mn-doped ZnO thin films, probed by electron paramagnetic resonance. *Journal of Materials Chemistry C*, **2014**, 2, 4947	7.1	26
247	Fresnoite thin films grown by pulsed laser deposition: photoluminescence and laser crystallization. *CrystEngComm*, **2011**, 13, 6377	3.3	26
246	Magnetoresistance effects in Zn0.90Co0.10O films. *Journal of Applied Physics*, **2006**, 100, 013904	2.5	26
245	Exchange bias and magnetodielectric coupling effects in ZnFe2O4BaTiO3 composite thin films. *CrystEngComm*, **2012**, 14, 6477	3.3	25

244	Ferroelectric thin film field-effect transistors based on ZnO/BaTiO3 heterostructures. *Journal of Vacuum Science & Technology B*, **2009**, 27, 1789		25
243	Electrical properties of ZnO thin films and optical properties of ZnO-based nanostructures. *Superlattices and Microstructures*, **2005**, 38, 317-328	2.8	25
242	Epitaxial Coherence at Interfaces as Origin of High Magnetoelectric Coupling in Multiferroic BaTiO3BiFeO3 Superlattices. *Advanced Materials Interfaces*, **2016**, 3, 1500822	4.6	25
241	Intense white photoluminescence emission of V-implanted zinc oxide thin films. *Journal of Applied Physics*, **2008**, 104, 123504	2.5	24
240	Properties of phosphorus doped ZnO. *Applied Physics A: Materials Science and Processing*, **2007**, 88, 125-128	2.6	24
239	Epitaxial stabilization of single phase (InxGa1)2O3 thin films up to x = 0.28 on c-sapphire and Ga2O3(001) templates by tin-assisted VCCS-PLD. *APL Materials*, **2019**, 7, 101102	5.7	24
238	Properties of Schottky Barrier Diodes on (In(x)Ga(1-x))For 0.01x0.85 Determined by a Combinatorial Approach. *ACS Combinatorial Science*, **2015**, 17, 710-5	3.9	23
237	On the transition point of thermally activated conduction of spinel-type MFe2O4 ferrite thin films (M = Zn, Co, Ni). *Applied Physics Letters*, **2013**, 102, 172104	3.4	23
236	Ferrimagnetic ZnFe2O4 thin films on SrTiO3 single crystals with highly tunable electrical conductivity. *Physica Status Solidi - Rapid Research Letters*, **2011**, 5, 438-440	2.5	23
235	Tuning the lateral density of ZnO nanowire arrays and its application as physical templates for radial nanowire heterostructures. *Journal of Materials Chemistry*, **2010**, 20, 3848		23
234	Room temperature ferromagnetism in Nd- and Mn-codoped ZnO films. *Journal Physics D: Applied Physics*, **2008**, 41, 105012	3	23
233	EPR study on magnetic Zn1MnxO. *Superlattices and Microstructures*, **2005**, 38, 413-420	2.8	23
232	Inductive determination of the critical current density of superconducting thin films without lateral structuring. *Physica C: Superconductivity and Its Applications*, **1994**, 220, 209-214	1.3	23
231	Magnetic spin structure and magnetoelectric coupling in BiFeO3-BaTiO3 multilayer. *Applied Physics Letters*, **2015**, 106, 082904	3.4	22
230	Electrical properties of ZnOBaTiO3ZnO heterostructures with asymmetric interface charge distribution. *Applied Physics Letters*, **2009**, 95, 082902	3.4	22
229	Optical whispering gallery modes in dodecagonal zinc oxide microcrystals. *Superlattices and Microstructures*, **2007**, 42, 333-336	2.8	22
228	Homoepitaxial ZnO thin films by PLD: Structural properties. *Physica Status Solidi C: Current Topics in Solid State Physics*, **2008**, 5, 3280-3287		22
227	Electronic and optical properties of ZnO/(Mg,Zn)O quantum wells with and without a distinct quantum-confined Stark effect. *Journal of Applied Physics*, **2012**, 111, 063701	2.5	21

226	Oxide Thin Film Heterostructures on Large Area, with Flexible Doping, Low Dislocation Density, and Abrupt Interfaces: Grown by Pulsed Laser Deposition. *Laser Chemistry*, **2010**, 2010, 1-27		21
225	Origin of the near-band-edge luminescence in MgxZn1−xO alloys. *Journal of Applied Physics*, **2010**, 107, 013704	2.5	21
224	Excitonic transport in ZnO. *Journal of Materials Research*, **2012**, 27, 2225-2231	2.5	20
223	Low temperature photoluminescence and infrared dielectric functions of pulsed laser deposited ZnO thin films on silicon. *Thin Solid Films*, **2006**, 496, 234-239	2.2	20
222	Dielectric properties of Fe-doped BaxSr1−xTiO3 thin films on polycrystalline substrates at temperatures between −35 and +85 °C. *Solid-State Electronics*, **2003**, 47, 2199-2203	1.7	20
221	Room-temperature cathodoluminescence of n-type ZnO thin films grown by pulsed laser deposition in N2, N2O, and O2 background gas. *Thin Solid Films*, **2005**, 486, 205-209	2.2	20
220	Charge transfer-induced magnetic exchange bias and electron localization in (111)- and (001)-oriented LaNiO3/LaMnO3 superlattices. *Applied Physics Letters*, **2017**, 110, 102403	3.4	19
219	Interface-Charge-Coupled Polarization Response of Pt-BaTiO3-ZnO-Pt Heterojunctions: A Physical Model Approach. *Journal of Electronic Materials*, **2008**, 37, 1029-1034	1.9	19
218	Comparative study of optical and magneto-optical properties of normal, disordered, and inverse spinel-type oxides. *Physica Status Solidi (B): Basic Research*, **2016**, 253, 429-436	1.3	18
217	Magnetoresistance in pulsed laser deposited 3d transition metal doped ZnO films. *Thin Solid Films*, **2006**, 515, 2549-2554	2.2	18
216	Solubility limit and material properties of a α-(AlxGa1−x)2O3 thin film with a lateral cation gradient on (00.1)Al2O3 by tin-assisted PLD. *APL Materials*, **2020**, 8, 021103	5.7	17
215	Visible emission from ZnCdO/ZnO multiple quantum wells. *Physica Status Solidi - Rapid Research Letters*, **2012**, 6, 31-33	2.5	17
214	Stable p-type ZnO:P nanowire/n-type ZnO:Ga film junctions, reproducibly grown by two-step pulsed laser deposition. *Journal of Vacuum Science & Technology B*, **2009**, 27, 1693		17
213	Comparative characterization of differently grown ZnO single crystals by positron annihilation and Hall effect. *Superlattices and Microstructures*, **2007**, 42, 259-264	2.8	17
212	Structural and optical properties of ZrO2 and Al2O3 thin films and Bragg reflectors grown by pulsed laser deposition. *Physica Status Solidi C: Current Topics in Solid State Physics*, **2008**, 5, 1240-1243		17
211	Epitaxial α-(AlxGa1−x)2O3 thin films and heterostructures grown by tin-assisted VCCS-PLD. *APL Materials*, **2019**, 7, 111110	5.7	17
210	Correlation of Interface Impurities and Chemical Gradients with High Magnetoelectric Coupling Strength in Multiferroic BiFeO-BaTiO Superlattices. *ACS Applied Materials & Interfaces*, **2017**, 9, 18956-18965	9.5	16
209	Suppression of Grain Boundary Scattering in Multifunctional p-Type Transparent δ-CuI Thin Films due to Interface Tunneling Currents. *Advanced Materials Interfaces*, **2018**, 5, 1701411	4.6	16

208	Modeling the electrical transport in epitaxial undoped and Ni-, Cr-, and W-doped TiO2 anatase thin films. *Applied Physics Letters*, **2014**, 105, 062103	3.4	16
207	(Zn,Cd)O thin films for the application in heterostructures: Structural and optical properties. *Journal of Applied Physics*, **2012**, 112, 103517	2.5	16
206	Temperature dependence of localization effects of excitons in ZnO□dxZn1□xO□ZnO double heterostructures. *Journal of Vacuum Science & Technology B*, **2009**, 27, 1741		16
205	Ion beam analysis of epitaxial (Mg, Cd)xZn1□xO and ZnO:(Li, Al, Ga, Sb) thin films grown on c-plane sapphire. *Nuclear Instruments & Methods in Physics Research B*, **2004**, 219-220, 891-896	1.2	16
204	Dependence of Trap Concentrations in ZnO Thin Films on Annealing Conditions. *Journal of the Korean Physical Society*, **2008**, 53, 2861-2863	0.6	16
203	Anisotropic strain relaxation through prismatic and basal slip in □(Al, Ga)2O3 on R-plane Al2O3. *APL Materials*, **2020**, 8, 021108	5.7	15
202	Induced ferromagnetism and magnetoelectric coupling in ion-beam synthesized BiFeO3□CoFe2O4nanocomposite thin films. *Journal Physics D: Applied Physics*, **2016**, 49, 325302	3	15
201	Defect-induced magnetism in homoepitaxial manganese-stabilized zirconia thin films. *Journal Physics D: Applied Physics*, **2013**, 46, 275002	3	15
200	Nonlinear ac susceptibility of high temperature superconducting rings. *Applied Physics Letters*, **1997**, 70, 898-900	3.4	15
199	ZnO based planar and micropillar resonators. *Superlattices and Microstructures*, **2007**, 41, 360-363	2.8	15
198	Co location and valence state determination in ferromagnetic ZnO:Co thin films by atom-location-by-channeling-enhanced-microanalysis electron energy-loss spectroscopy. *Applied Physics Letters*, **2007**, 90, 154101	3.4	15
197	Advances of pulsed laser deposition of ZnO thin films. *Annalen Der Physik*, **2004**, 13, 59-60	2.6	15
196	Dielectric loss tangent of sapphire single crystal produced by edge-defined film-fed growth method. *Physica C: Superconductivity and Its Applications*, **2002**, 377, 313-318	1.3	15
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194	Layer-by-layer growth of TiN by pulsed laser deposition on in-situ annealed (100) MgO substrates. *Physica Status Solidi (A) Applications and Materials Science*, **2014**, 211, 2621-2624	1.6	14
193	Degenerate interface layers in epitaxial scandium-doped ZnO thin films. *Journal Physics D: Applied Physics*, **2013**, 46, 065311	3	14
192	Vacuum ultraviolet dielectric function of ZnFe2O4 thin films. *Journal of Applied Physics*, **2013**, 113, 073503	2.5	14
191	Identification of a donor-related recombination channel in ZnO thin films. *Physical Review B*, **2010**, 81,	3.3	14

190	Luminescence properties of ZnO/Zn1−xCdxO/ZnO double heterostructures. *Journal of Applied Physics*, **2010**, 107, 093530	2.5	14
189	ZnO-based metal-semiconductor field-effect transistors on glass substrates. *Applied Physics Letters*, **2009**, 95, 153503	3.4	14
188	Resistivity control of ZnO nanowires by Al doping. *Physica Status Solidi - Rapid Research Letters*, **2010**, 4, 82-84	2.5	14
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186	Deep defects generated in n-conducting ZnO:TM thin films. *Solid State Communications*, **2006**, 137, 417-421	1.8	14
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182	Large Area Pulsed Laser Deposition of YBCO Thin Films and Buffer Layers on 3-Inch Wafers. *Materials Research Society Symposia Proceedings*, **1994**, 341, 189		14
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